MOSFETs Silicon N-channel MOS (U-MOSIX-H)

TPHR6503PL

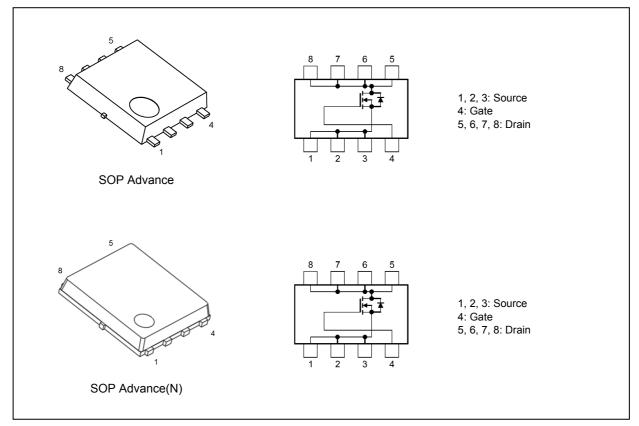
1. Applications

- High-Efficiency DC-DC Converters
- Switching Voltage Regulators

2. Features

- (1) High-speed switching
- (2) Small gate charge: $Q_{SW} = 30 \text{ nC}$ (typ.)
- (3) Small output charge: $Q_{oss} = 81.3 \text{ nC}$ (typ.)
- (4) Low drain-source on-resistance: $R_{DS(ON)} = 0.41 \text{ m}\Omega$ (typ.) ($V_{GS} = 10 \text{ V}$)
- (5) Low leakage current: $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 30 \ V)$
- (6) Enhancement mode: V_{th} = 1.1 to 2.1 V (V_{DS} = 10 V, I_D = 1.0 mA)

3. Packaging and Internal Circuit



The package can be selected according to your preference. For details, please contact your TOSHIBA sales representative.

4. Absolute Maximum Ratings (Note) (T_a = 25 °C unless otherwise specified)

Characteris	tics		Symbol	Rating	Unit
Drain-source voltage			V _{DSS}	30	V
Gate-source voltage		(Note 1)	V _{GSS}	±20	
Drain current (DC)	(T _c = 25 °C)	(Note 2)	Ι _D	150	A
Drain current (DC)	(Silicon limit)	(Note 2), (Note 3)	Ι _D	393	A
Drain current (pulsed)	(t = 100 μs)	(Note 2)	I _{DP}	500	A
Power dissipation	(T _c = 25 °C)		PD	170	W
Power dissipation		(Note 4)	PD	3.0	W
Power dissipation		(Note 5)	PD	0.96	W
Single-pulse avalanche energy		(Note 6)	E _{AS}	374	mJ
Single-pulse avalanche current	·	(Note 6)	I _{AS}	120	A
Channel temperature			T _{ch}	175	°C
Storage temperature			T _{stg}	-55 to 175	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

Characteristics			Symbol	Max	Unit
Channel-to-case thermal resistance	(T _c = 25 °C)		R _{th(ch-c)}	0.88	°C/W
Channel-to-ambient thermal resistance	(T _a = 25 °C)	(Note 4)	R _{th(ch-a)}	50	
Channel-to-ambient thermal resistance	(T _a = 25 °C)	(Note 5)	R _{th(ch-a)}	156	

Note 1: +20V /-16V ensured at DC condition.

-20V ensured at pulse condition(duty 5%).

Note 2: Ensure that the channel temperature does not exceed 175 °C.

Note 3: Limited by silicon chip capability. Package limit is 150 A.

Note 4: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 5: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 6: V_{DD} = 24 V, T_{ch} = 25 °C (initial), L = 0.02 mH, I_{AS} = 120 A

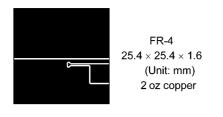
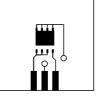
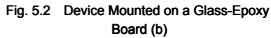


Fig. 5.1 Device Mounted on a Glass-Epoxy

Board (a)



FR-4 25.4 × 25.4 × 1.6 (Unit: mm) 2 oz copper



Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

6.1. Static Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	V_{GS} = ±20 V, V_{DS} = 0 V	_		±0.1	μA
Drain cut-off current	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V	_		10	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10 mA, V _{GS} = 0 V	30		_	V
	V _{(BR)DSX}	I _D = 10 mA, V _{GS} = -20 V	15	_	_	
Gate threshold voltage	V _{th}	V _{DS} = 10 V, I _D = 1.0 mA	1.1	_	2.1	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = 4.5 V, I _D = 50 A	_	0.6	0.89	mΩ
		V _{GS} = 10 V, I _D = 50 A	_	0.41	0.65	

6.2. Dynamic Characteristics ($T_a = 25$ °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = 15 V, V _{GS} = 0 V, f = 1 MHz	_	7700	10000	pF
Reverse transfer capacitance	C _{rss}		_	220	—	
Output capacitance	C _{oss}			2720	_	
Gate resistance	r _g	—	_	0.6	1.1	Ω
Switching time (rise time)	t _r	See Fig. 6.2.1	_	12	_	ns
Switching time (turn-on time)	t _{on}			36	_	
Switching time (fall time)	t _f]		10	_	
Switching time (turn-off time)	t _{off}		_	100	_	

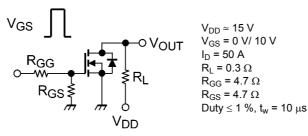


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25$ °C unless otherwise specified)

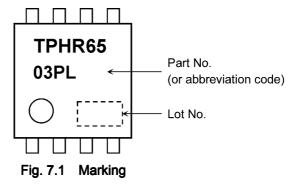
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus	Qg	$V_{DD}\approx 15~V,~V_{GS}\text{ = }10~V,~I_{D}\text{ = }50~A$	_	110	_	nC
gate-drain)		$V_{DD} \approx 15$ V, V_{GS} = 4.5 V, I_D = 50 A	_	52	_	
Gate-source charge 1	Q _{gs1}	$V_{DD} \approx 15$ V, V_{GS} = 10 V, I_D = 50 A	_	24	_	
Gate-drain charge	Q _{gd}		—	16	_	
Gate switch charge	Q _{SW}		_	30	_	
Output charge	Q _{oss}	V _{DS} = 15 V, V _{GS} = 0 V, f = 1 MHz	_	81.3	_	

6.4. Source-Drain Characteristics ($T_a = 25$ °C unless otherwise specified)

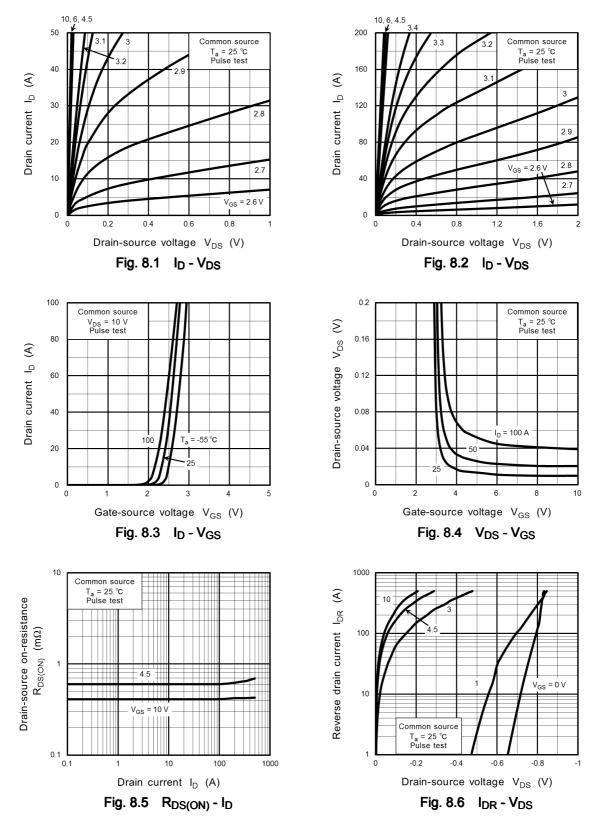
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (pulsed) (N	lote 7)	I _{DRP} (t = 100 μs)	_	Ι		500	A
Diode forward voltage		V _{DSF}	I _{DR} = 150 A, V _{GS} = 0 V			-1.2	V
Reverse recovery time			V_R = 15 V, I_{DR} = 37.5 A, V_{GS} =		59	—	ns
Reverse recovery charge		Q _{rr}	0 V, -dI _{DR} /dt = 100 A/μs	_	70	_	nC

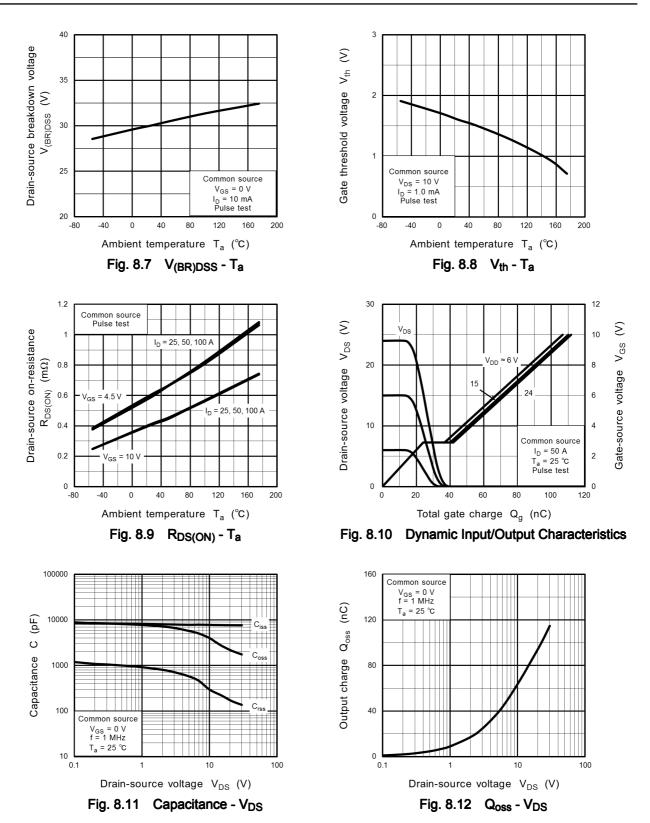
Note 7: Ensure that the channel temperature does not exceed 175 °C.

7. Marking

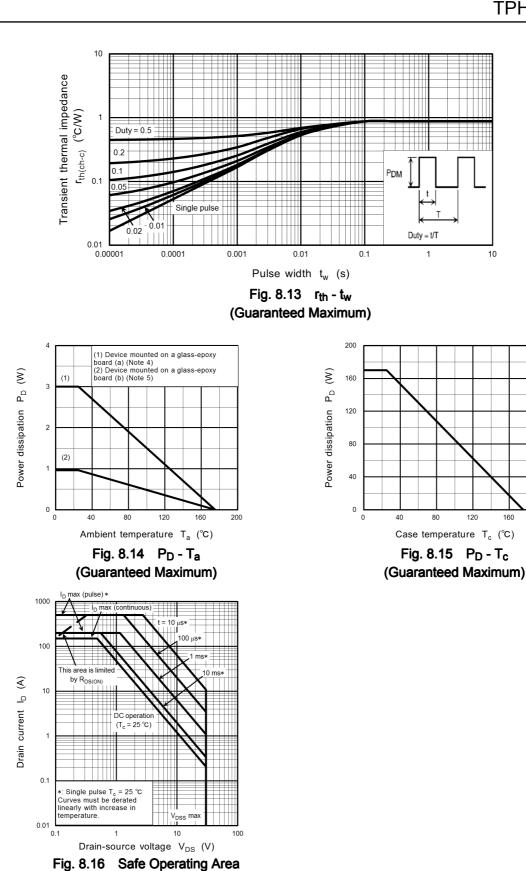


8. Characteristics Curves (Note)





200



Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

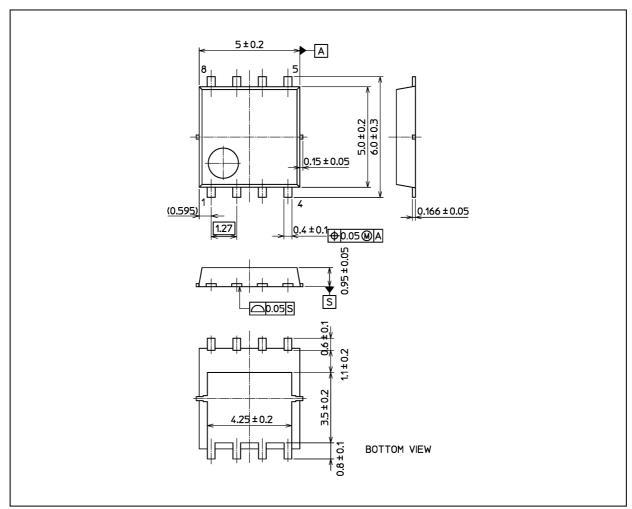
(Guaranteed Maximum)

TOSHIBA

TPHR6503PL

Package Dimensions

Unit: mm



The package can be selected according to your preference. For details, please contact your TOSHIBA sales representative.

Weight: 0.087 g (typ.)

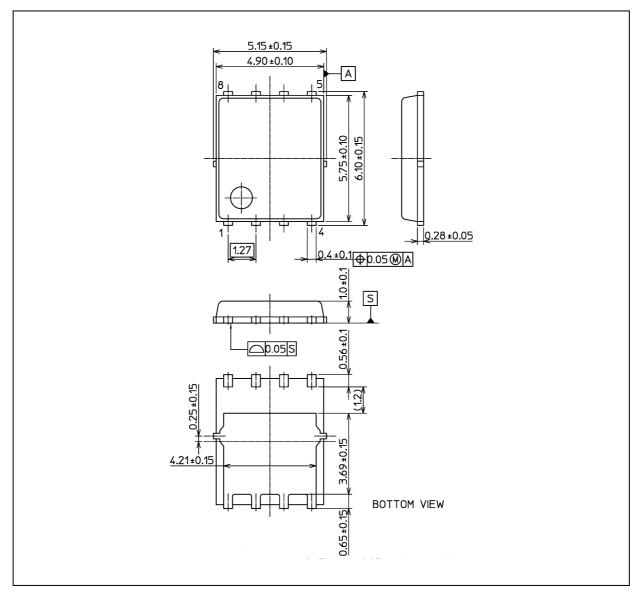
	Package Name(s)
TOSHIBA: 2-5Q1S	
Nickname: SOP Advance	



TPHR6503PL

Package Dimensions

Unit: mm



The package can be selected according to your preference. For details, please contact your TOSHIBA sales representative.

Weight: 0.111 g (typ.)

Package Name(s)
TOSHIBA: 2-5W1A
Nickname: SOP Advance(N)

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